# MSKSEMI 美森科













**ESD** 

T

TSS

MOV

GDI

PLED

AZ9143-08F

**Product specification** 





#### **Features**

- 150 Watts peak pulse power (tp = 8/20µs)
- Transient protection for high speed data lines to
   IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
   IEC 61000-4-4 (EFT) 40A (5/50ns)
- Working voltages: 3.3V
- Protects eight I/O lines
- Low operating and clamping voltages
- Solid-state silicon avalanche technology

## **Application**

- Notebooks, Desktops, Servers and Video Graphics Cards
- USB Power & Data Line Protection
- Monitors and Flat Panel Displays
- I<sup>2</sup>C Bus Protection
- Portable Instrumentation
- Set Top Box

#### **Reference News**

PACKAGE OUTLINE Pin Configuration		Marking
DFN3810-9L	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	ULC9 • 3328



## Maximum Rating @ Ta=25 $^{\circ}$ C unless otherwise specified

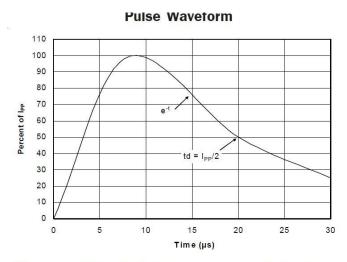
Symbol	Parameter	Ratings	Units
Ррк	Peak Pulse Power (tp = 8/20µs)	150	Watts
TL	Lead Soldering Temperature	260( 10sec.)	${\mathbb C}$
TJ	Operating Temperature	-55 to + 125	${\mathbb C}$
Тѕтс	Storage Temperature	-55 to + 150	${\mathbb C}$

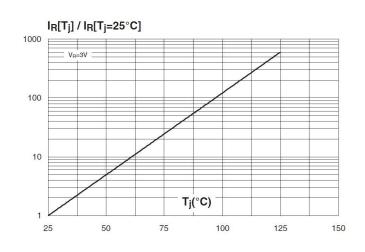
## Electrical Characteristics@ Ta=25℃ unless otherwise

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V <sub>RWM</sub>	Reverse Working Voltage	Any I/O to Ground			3.3	V
V <sub>BR</sub>	Reverse Breakdown Voltage	I <sub>T</sub> = 1mA, Any I/O to Ground	4.5			V
lR	Reverse Leakage Current	V <sub>RWM</sub> = 5V, Any I/O to Ground			1	μA
	Olamaria a Malkana	IPP = 1A, tp =8/20μs, any I/O pin to Ground			9.8	V
Vc	V <sub>C</sub> Clamping Voltage	I <sub>PP</sub> = 3A, tp =8/20µs, any I/O pin to Ground			15	V
CJ	Junction Capacitance	V <sub>R</sub> = 0V, f =1MHz, between I/O pins		0.3	0.5	pF
		V <sub>R</sub> = 0V, f =1MHz, any I/O pin to Ground		0.5	0.8	pF

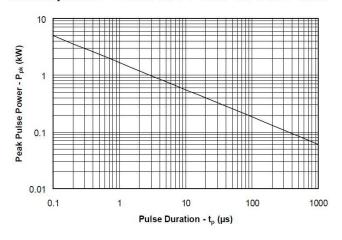


## Typical Characteristics@ Ta=25℃ unless otherwise specified

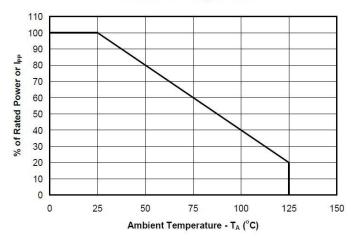




#### Non-Repetitive Peak Pulse Power vs. Pulse Time

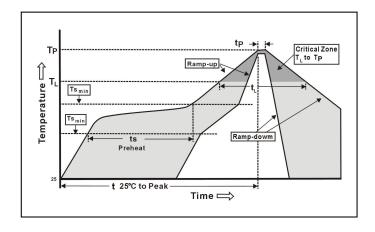


#### **Power Derating Curve**



## **Soldering Parameters**

Reflow Condition		Fb — Free assembly	
	-Temperature Min (T <sub>s(Min)</sub> )	150°C	
Pre Heat	- Temperature Max (T <sub>s(Max)</sub> )	200°C	
	-Time (Min to max) (t <sub>s</sub> )	60 – 180 secs	
Average ramp up rate (Liquidus) Temp (T <sub>L</sub> ) to peak		3°C/second Max	
T <sub>S (Max)</sub> to T <sub>L</sub> - Ramp-up Rate		3°C/second Max	
Reflow	-Temperature (T <sub>L</sub> ) (Liquidus)	217°C	
Kellow	-Temperature (t <sub>L</sub> )	60 – 150 seconds	
Peak Temperature (T <sub>p</sub> )		250 <sup>+0/-5</sup> °C	
Time within 5°C of actual peak Temperature (t <sub>p</sub> )		20 – 40 seconds	
Ramp-dowm Rate		6°C/second Max	
Time 25°C to peak Temperature (T <sub>p</sub> )		8 minutes Max.	
Do not exceed		260°C	

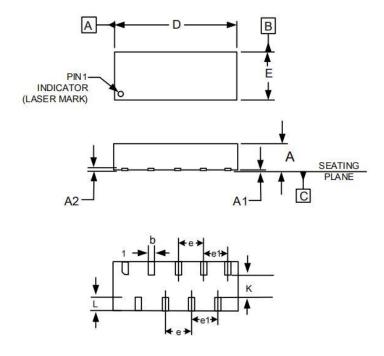




## **Package Outline**

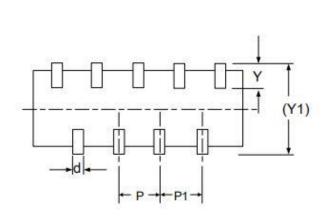
Plastic surface mounted package

**DFN3810** 



DIM	MILLIMETERS		
DIM -	MIN	NOM	MAX
D	3.70	3.80	3.90
E	0.90	1.00	1.10
Α	0.45	0.50	0.55
A1	0.00	0.02	0.05
A2	0.10	0.15	0.20
b	0.15	0.20	0.25
е	0.80BSC		
e1	0.90BSC		
L	0.20	0.30	0.40

# **Soldering Footprint**



DIMENSIONS			
DIM	INCHES	MILLIMETERS	
Р	0.031	0.80	
P1	0.035	0.90	
d	0.012	0.30	
Υ	0.024	0.60	
Y1	0.061	1.55	

# ${\bf Package And Marking Information}$

P/N	PKG	QTY
AZ9143-08F	DFN3810	3000



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